## NSN 5961-00-464-2495

Transistor - Page 1 of 1

No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-464-2495 **Inclosure Material:** Metal **Overall Length:** Between 0.500 inches and 0.535 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case: Emitter Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.865 inches and 0.875 inches **Thread Size:** 0.512 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 collector to base voltage, dc and 25.0 collector to emitter voltage, dc and 5.0 base to emitter voltage, dc **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator: Terminal Type And Quantity:** 1 wire hook and 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**